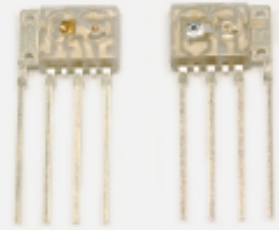


# Transmitter/Receiver photo IC for optical link L10063-01, S10064-01

For MOST automotive network, 50 Mbps band POF communications



L10063-01 and S10064-01 are transmitter and receiver photo ICs developed for MOST (Media Oriented System Transport) networks used in vehicles to communicate multimedia information. The transmitter photo IC L10063-01 consists of a red LED and driver IC incorporated into a clear plastic package and can be set to an operating mode that reduces the optical output level by half. The receiver photo IC S10064-01 is a monolithic photo IC fabricated by the PiN-BiP process and features a wide dynamic range. It also has a low power consumption "sleeping mode" and an optical wakeup mode triggered by input of light. Both the transmitter and receiver photo IC input or output digital signals through a TTL interface.

## Features

### L10063-01

- Wide operating temperature range: -40 to +105 °C
- DC to 50 Mbps data communications
- TTL input
- Optical output 50 % cut mode

### S10064-01

- Wide operating temperature range: -40 to +105 °C
- 4 M to 50 Mbps data communications
- Monolithic structure immune from external noise
- TTL output
- Wide dynamic range
- Sleeping mode with optical wakeup

### ■ Absolute maximum ratings \*1 (Ta= -40 to +105 °C)

Parameter	Symbol	L10063-01, S10064-01	Unit
Supply voltage	Vcc	-0.5 to +7.0	V
Operating temperature	Topr	-40 to +105	°C
Storage temperature	Tstg	-40 to +120	°C
Soldering	Tsol	260 °C, 5 s, 3 times, at least 2.5 mm away from lead root	-

## Applications

- Only for vehicle networks (MOST)

### MOST compliant products

Specifications of these products are subject to change without prior notice to keep up with changes in the MOST standard.

## S10064-01

### ■ Electrical and optical characteristics (Ta= -40 to +105 °C, Vcc=4.75 to 5.25 V \*1)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Current consumption (operation mode)	Icco	*2	-	-	30	mA
Current consumption (sleeping mode)	Iccs	Dark state	-	-	20	µA
Receiver level	Popt3	Bi-phase signal	-25	-	-2	dBm
Vout	High level output voltage	Ioh= -150 µm	2.5	-	Vcc+0.3	V
	Low level output voltage	Iol=1.6 mA	0	-	0.4	V
	Rise time	10 to 90 % *2, *3	-	-	9	ns
	Fall time		tf	-	-	
Pulse width variation	tpwv	*2, *3, *4, *6	17.9	-	29.79	ns
Pulse width distortion (average value)	tapwd	*2, *3, *4, *6	-2.69	-	+6.49	ns
Operation to sleeping mode transition receivable level	PsI	*2, *5	-39	-	-25.5	dBm
Sleeping mode to operation transition receivable level	Pop					
Mode output	High level voltage	Vmh	I <sub>mh</sub> = -20 µA	4.0	-	V
	Low level voltage	Vml	I <sub>ml</sub> =0.88 mA	-	-	0.5

\*1: A bypass capacitor (0.1 µF) is connected between Vcc and GND at a position within 3 mm from the lead, and a 10 µF capacitor is also connected to the power supply line nearby.

The center of the optical fiber is aligned with the center of the package lens.

The distance between the fiber end and the lens top is 0.1 mm.

\*2: Measured with input signals conforming to SP3 MOST specification of physical layer Rev 1.1 Addendum B.

\*3: Measured with RL=50 kΩ, CL=15 pF (including parasitic capacitance such as probe, connector and evaluation circuit board pattern), and threshold voltage 1.5 V.

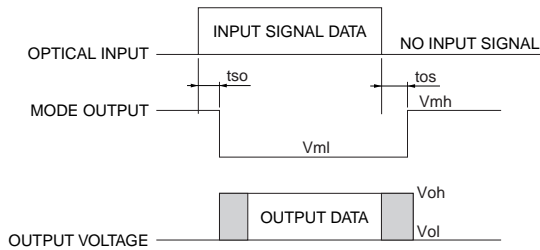
\*4: An optical input waveform is generated with a Hamamatsu standard transmitter.

\*5: Average optical output is measured with a POF (NA=0.5).

\*6: Measured with BiPhase PRBS at 45.2 Mbps (NRZ signal conversion).

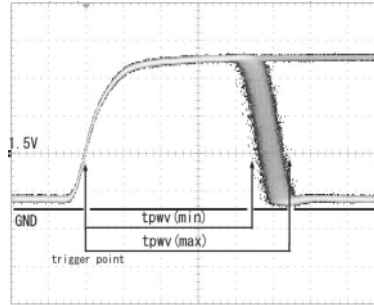
Note) • If modulated light at 4 Mbps or less (including DC light and no light input) is input to S10064-01, the high and low levels cannot be discerned.

## Mode output waveform



KPIC00095EA

## Output waveform example



Vertical axis: 1 V/div., Horizontal axis: 5 ns/div.  
 (Ta=25 °C, Vcc=5.25 V, Pi= -26 dBm, RL=50 kΩ, CL=15 pF, 45.2 Mbps)

### L10063-01

#### Electrical and optical characteristics (Ta= -40 to +105 °C, Vcc= 4.75 to 5.25 V \*7)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Current consumption	Icc	Vin= 2.0 V, Rcont=13.5 kΩ	-	-	40	mA
Peak emission wavelength	λp		630	650	670	nm
Spectral half width (FWHM)	Δλ		-	20	30	nm
Fiber coupled optical output 1	Po1	Rcont=13.5 kΩ *8, *9	-9	-	-2	dBm
Fiber coupled optical output 2	Po2	Rcont=27 kΩ *8, *9	-12.5	-	-4.5	dBm
Extinction ratio	re		10	-	-	dB
Rise time at pulse drive	tr	20 to 80 % *8	-	-	6.0	ns
Fall time at pulse drive	tf	80 to 20 % *8	-	-	6.0	ns
Pulse width variation	tpwv	50 % *8, *10	19.99	-	24.29	ns
Pulse width distortion (average value)	tapwd	50 % *8, *10	-1.39	-	+1.39	ns

\*7: A bypass capacitor (0.1 μF) connected between Vcc and GND at a position within 3 mm from the lead, and a 10 μF capacitor is also connected to the power supply line nearby.

The center of the optical fiber is aligned with the center of the package lens.

The distance between the fiber end and the lens top is 0.1 mm.

\*8: Measured with input signals conforming to SP1 MOST specification of physical layer Rev 1.1 Addendum B.

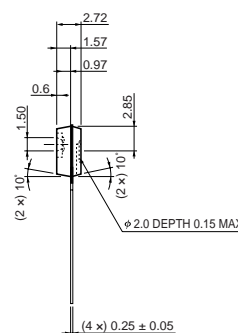
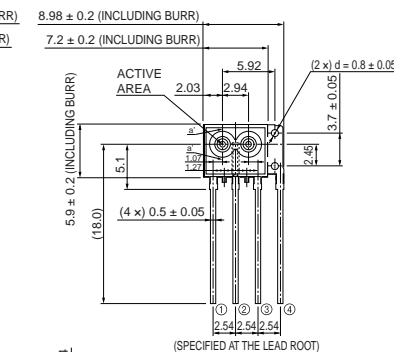
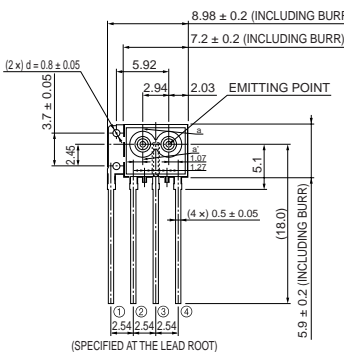
\*9: Average value measured with a plastic fiber (φ1 mm, SI-POF, NA=0.5, 1 m) made by Mitsubishi Rayon.

\*10: Measured with BiPhase PRBS at 45.2 Mbps (NRZ signal conversion).

## Dimensional outlines (unit: mm)

### L10063-01

### S10064-01



Tolerance unless otherwise noted: ±0.1, ±2°  
 R0.3 MAX.  
 Values in parentheses indicate reference value.  
 Lead surface finish: Pd plating  
 Shaded area indicates burr.

Pin No.	L10063-01	S10064-01
①	Vin	Vcc
②	GND	GND
③	Vcc	MODEOUT
④	Cont	Vout

a-a' CROSS SECTION

KPIC00067EA